# MUN2111, MMUN2111L, MUN5111, DTA114EE, DTA114EM3, NSBA114EF3

# **Digital Transistors (BRT)** R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

# PNP Transistors with Monolithic Bias Resistor Network

This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base–emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### **MAXIMUM RATINGS** (T<sub>A</sub> = $25^{\circ}$ C)

Rating	Symbol	Max	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc
Collector–Emitter Voltage	V <sub>CEO</sub>	50	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	100	mAdc
Input Forward Voltage	V <sub>IN(fwd)</sub>	40	Vdc
Input Reverse Voltage	V <sub>IN(rev)</sub>	10	Vdc

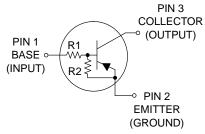
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

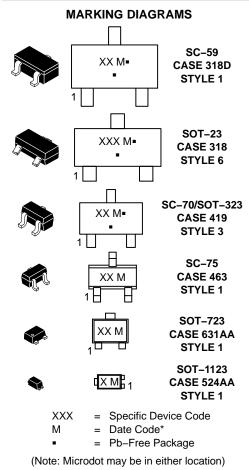


## **ON Semiconductor®**

www.onsemi.com







\*Date Code orientation may vary depending upon manufacturing location.

### **ORDERING INFORMATION**

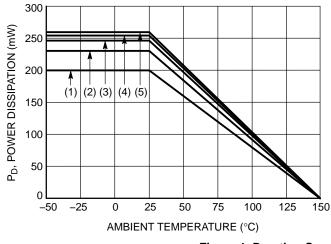
See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet.

# MUN2111, MMUN2111L, MUN5111, DTA114EE, DTA114EM3, NSBA114EF3

Table 1.	ORDERING	INFORMATION
----------	----------	-------------

Device	Part Marking	Package	Shipping <sup>†</sup>
MUN2111T1G, SMUN2111T1G	6A	SC–59 (Pb–Free)	3000 / Tape & Reel
SMUN2111T3G	6A	SC–59 (Pb–Free)	10000 / Tape & Reel
MMUN2111LT1G, SMMUN2111LT1G	A6A	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMUN2111LT3G, SMMUN2111LT3G	A6A	SOT-23 (Pb-Free)	10000 / Tape & Reel
MUN5111T1G, SMUN5111T1G	6A	SC-70/SOT-323 (Pb-Free)	3000 / Tape & Reel
DTA114EET1G, NSVDTA114EET1G	6A	SC-75 (Pb-Free)	3000 / Tape & Reel
DTA114EM3T5G, NSVDTA114EM3T5G	6A	SOT-723 (Pb-Free)	8000 / Tape & Reel
NSBA114EF3T5G	F	SOT-1123 (Pb-Free)	8000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



(1) SC-75 and SC-70/SOT-323; Minimum Pad
(2) SC-59; Minimum Pad
(3) SOT-23; Minimum Pad
(4) SOT-1123; 100 mm<sup>2</sup>, 1 oz. copper trace
(5) SOT-723; Minimum Pad

Figure 1. Derating Curve

## MUN2111, MMUN2111L, MUN5111, DTA114EE, DTA114EM3, NSBA114EF3

### **Table 2. THERMAL CHARACTERISTICS**

	Characteristic	Symbol	Max	Unit
THERMAL CHARACTERISTI	CS (SC–59) (MUN2111)			
Total Device Dissipation $T_A = 25^{\circ}C$ (Note 1)		PD	230	mW
(Note 2) Derate above 25°C (Note 2)	(Note 1)		338 1.8 2.7	mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 2)	R <sub>θJA</sub>	540 370	°C/W
Thermal Resistance, Junction to Lead (Note 2)	(Note 1)	R <sub>θJL</sub>	264 287	°C/W
Junction and Storage Temper	ature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTI	CS (SOT–23) (MMUN2111L)			
$\begin{array}{l} \mbox{Total Device Dissipation} \\ T_A = 25^\circ C \qquad (Note 1) \\ (Note 2) \\ \mbox{Derate above } 25^\circ C \\ (Note 2) \end{array}$	(Note 1)	PD	246 400 2.0 3.2	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 2)	$R_{\theta JA}$	508 311	°C/W
Thermal Resistance, Junction to Lead (Note 2)	(Note 1)	R <sub>θJL</sub>	174 208	°C/W
Junction and Storage Temper	ature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTI	CS (SC–70/SOT–323) (MUN5111)			
Total Device Dissipation $T_A = 25^{\circ}C$ (Note 1) (Note 2) Derate above 25^{C} (Note 2)	(Note 1)	PD	202 310 1.6 2.5	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 2)	R <sub>θJA</sub>	618 403	°C/W
Thermal Resistance, Junction to Lead (Note 2)	(Note 1)	R <sub>θJL</sub>	280 332	°C/W
Junction and Storage Temper	ature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTI	CS (SC–75) (DTA114EE)	· _ ·		
$\begin{array}{l} \mbox{Total Device Dissipation} \\ T_A = 25^\circ C & (Note 1) \\ (Note 2) \\ \mbox{Derate above } 25^\circ C \\ (Note 2) \end{array}$	(Note 1)	PD	200 300 1.6 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 2)	$R_{ heta JA}$	600 400	°C/W
Junction and Storage Temper	ature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTI	CS (SOT-723) (DTA114EM3)		-	
$\begin{array}{l} \mbox{Total Device Dissipation} \\ T_A = 25^\circ C \qquad (Note 1) \\ (Note 2) \\ \mbox{Derate above } 25^\circ C \\ (Note 2) \end{array}$	(Note 1)	PD	260 600 2.0 4.8	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 2)	$R_{ heta JA}$	480 205	°C/W

2. FR-4 @ 1.0 x 1.0 Inch Pad.

FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air.
 FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

### **Table 2. THERMAL CHARACTERISTICS**

Characteristic	Symbol	Max	Unit
THERMAL CHARACTERISTICS (SOT-1123) (NSBA114EF3)			
$ \begin{array}{l} \mbox{Total Device Dissipation} \\ T_A = 25^\circ C & (Note 3) \\ & (Note 4) \\ \mbox{Derate above } 25^\circ C & (Note 3) \\ & (Note 4) \end{array} $	PD	254 297 2.0 2.4	mW mW/°C
Thermal Resistance,(Note 3)Junction to Ambient(Note 4)	$R_{ extsf{ heta}JA}$	493 421	°C/W
Thermal Resistance, Junction to Lead (Note 3)	R <sub>θJL</sub>	193	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

1. FR-4 @ Minimum Pad.

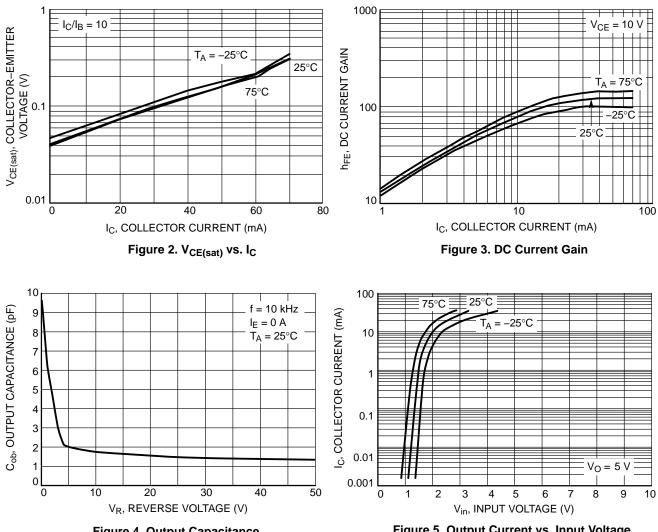
FR-4 @ 1.0 x 1.0 Inch Pad.
 FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air.
 FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

### Table 3. ELECTRICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ , unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Base Cutoff Current ( $V_{CB} = 50 \text{ V}, I_E = 0$ )	I <sub>СВО</sub>	_	_	100	nAdc
Collector–Emitter Cutoff Current ( $V_{CE} = 50 \text{ V}, I_B = 0$ )	I <sub>CEO</sub>	_	_	500	nAdc
Emitter–Base Cutoff Current ( $V_{EB} = 6.0 \text{ V}, I_C = 0$ )	I <sub>EBO</sub>	_	_	0.5	mAdc
Collector–Base Breakdown Voltage ( $I_C = 10 \ \mu A, I_E = 0$ )	V <sub>(BR)CBO</sub>	50	_	-	Vdc
Collector–Emitter Breakdown Voltage (Note 5) $(I_{C} = 2.0 \text{ mA}, I_{B} = 0)$	V <sub>(BR)CEO</sub>	50	_	-	Vdc
ON CHARACTERISTICS	•	•			
DC Current Gain (Note 5) $(I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V})$	h <sub>FE</sub>	35	60	_	
Collector–Emitter Saturation Voltage (Note 5) $(I_{C} = 10 \text{ mA}, I_{B} = 0.3 \text{ mA})$	V <sub>CE(sat)</sub>	-	_	0.25	Vdc
Input Voltage (off) $(V_{CE} = 5.0 \text{ V}, I_C = 100 \mu\text{A})$	V <sub>i(off)</sub>	-	1.2	0.8	Vdc
Input Voltage (on) ( $V_{CE} = 0.3 \text{ V}, I_C = 10 \text{ mA}$ )	V <sub>i(on)</sub>	2.5	1.8	_	Vdc
Output Voltage (on) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 2.5 V, R <sub>L</sub> = 1.0 k $\Omega$ )	V <sub>OL</sub>	-	_	0.2	Vdc
Output Voltage (off) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 0.5 V, R <sub>L</sub> = 1.0 k $\Omega$ )	V <sub>OH</sub>	4.9	_	_	Vdc
Input Resistor	R1	7.0	10	13	kΩ
Resistor Ratio	R <sub>1</sub> /R <sub>2</sub>	0.8	1.0	1.2	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product

performance may not be indicated by the Electrical Characteristics if operated under different conditions. 5. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle  $\leq 2\%$ .



**TYPICAL CHARACTERISTICS** MUN2111, MMUN2111L, MUN5111, DTA114EE, DTA114EM3

Figure 4. Output Capacitance

Figure 5. Output Current vs. Input Voltage

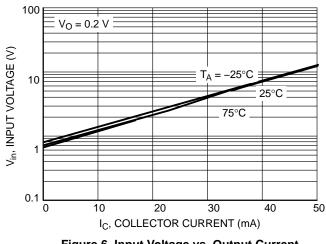
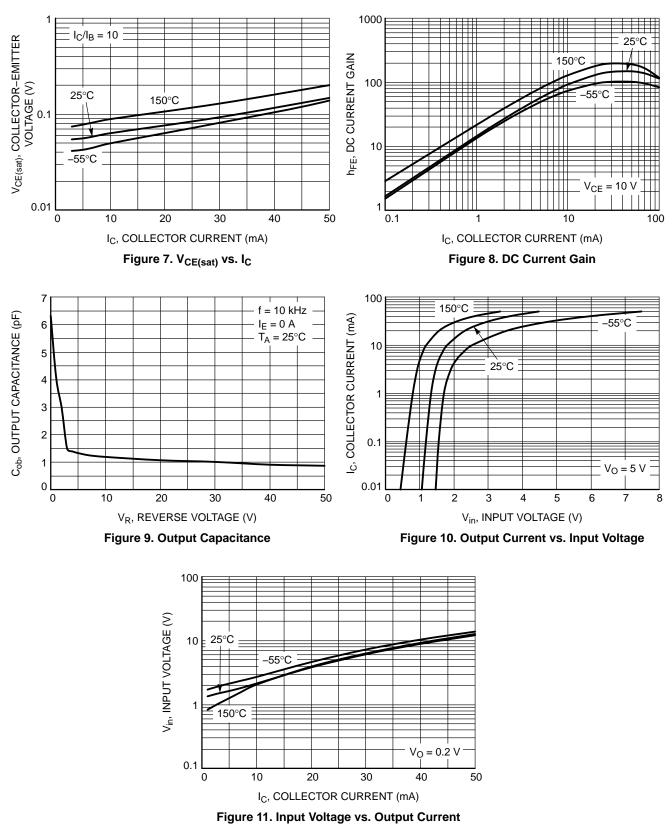


Figure 6. Input Voltage vs. Output Current

## MUN2111, MMUN2111L, MUN5111, DTA114EE, DTA114EM3, NSBA114EF3



### **TYPICAL CHARACTERISTICS – NSBA114EF3**

### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

D

3

TOP VIEW

SIDE VIEW

Нe

DETAIL A

-3X b

# onsemi



SCALE 4:1

A\_\_\_\_ ' A1SOT-23 (TO-236) CASE 318 ISSUE AT

0.25

-L1

DETAIL A

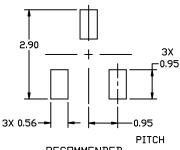
END VIEW

DATE 01 MAR 2023

NDTES

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIM	IETERS			INCHES	
DIM	MIN.	NDM.	MAX.	MIN.	NDM.	MAX.
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
с	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
Η <sub>E</sub>	2.10	2.40	2.64	0.083	0.094	0.104
Т	0*		10*	0*		10*



RECOMMENDED MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

# GENERIC MARKING DIAGRAM\*



XXX = Specific Device Code

M = Date Code

= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

## **STYLES ON PAGE 2**

DOCUMENT NUMBER:	98ASB42226B	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED 0	
DESCRIPTION:	SOT-23 (TO-236)		PAGE 1 OF 2
the right to make changes without furth purpose, nor does <b>onsemi</b> assume a	er notice to any products herein. <b>onsemi</b> make ny liability arising out of the application or use	LLC dba <b>onsemi</b> or its subsidiaries in the United States and/or other cours so no warranty, representation or guarantee regarding the suitability of its pr of any product or circuit, and specifically disclaims any and all liability, inc e under its patent rights nor the rights of others.	roducts for any particular

# MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

# onsemi

#### SOT-23 (TO-236) CASE 318 ISSUE AT

### DATE 01 MAR 2023

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE		
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

DOCUMENT NUMBER:	98ASB42226B Electronic versions are uncontrolled except when accessed directly from the Document Report Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	SOT-23 (TO-236)		PAGE 2 OF 2

onsemi and ONSEMi. are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.





SCALE 2:1



### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SC-59 CASE 318D-04 ISSUE H

DATE 28 JUN 2012

NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS				INCHES	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.00	1.15	1.30	0.039	0.045	0.051
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.35	0.43	0.50	0.014	0.017	0.020
С	0.09	0.14	0.18	0.003	0.005	0.007
D	2.70	2.90	3.10	0.106	0.114	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
е	1.70	1.90	2.10	0.067	0.075	0.083
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.80	3.00	0.099	0.110	0.118

#### GENERIC **MARKING DIAGRAM**



= Specific Device Code XXX Μ = Date Code

= Pb-Free Package\*

(\*Note: Microdot may be in either location)

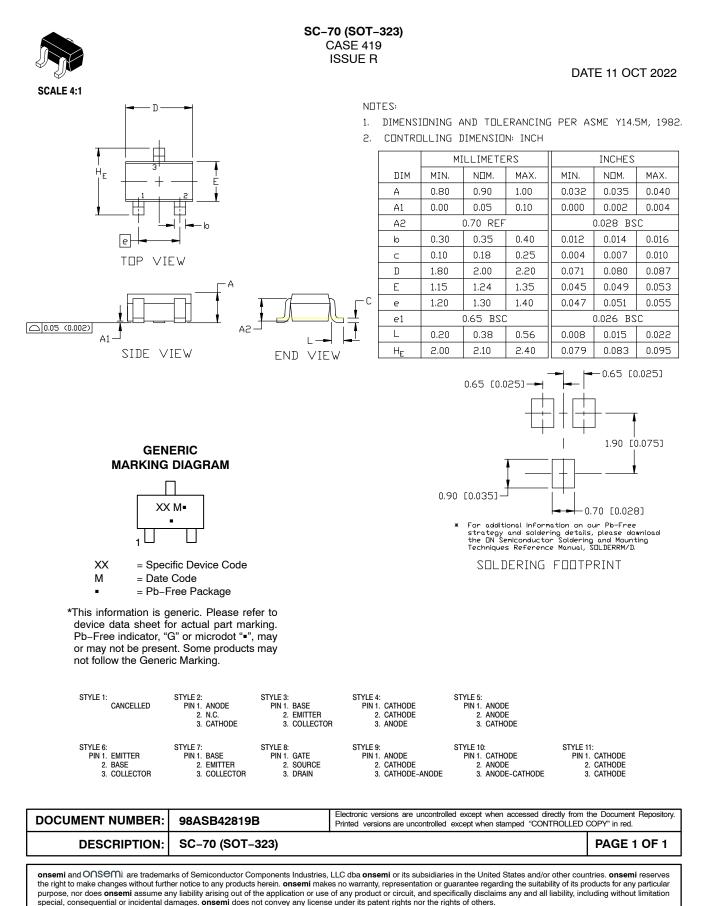
\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

STYLE 1:	STYLE 2:	STYLE 3:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE
2. EMITTER	2. N.C.	2. ANODE
3. COLLECTOR	3. CATHODE	3. CATHODE
Style 4:	Style 5:	STYLE 6:
Pin 1. Cathode	Pin 1. Cathode	PIN 1. ANODE
2. N.C.	2. Cathode	2. CATHODE
3. Anode	3. Anode	3. ANODE/CATHODE

DOCUMENT NUMBER:	98ASB42664B	Electronic versions are uncontrolled except when accessed directly from the Printed versions are uncontrolled except when stamped "CONTROLLED to the stamped "CONTROLLED to the stamped statement of the stamped statement of the s	
DESCRIPTION:	SC-59		PAGE 1 OF 1
the suitability of its products for any pa	are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. he right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding r any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically ncluding without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the		

### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

# onsemi







\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

1.000

0.039

SCALE 10:1

mm

inches

0.508

0.020

 
 DOCUMENT NUMBER:
 98ASB15184C
 Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

 DESCRIPTION:
 SC-75/SOT-416
 PAGE 1 OF 1

 ON Semiconductor and (iii) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its pattern rights nor the

rights of others.





SCALE 8:1



SOT-1123 CASE 524AA ISSUE C





#### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. GATE
2. EMITTER	2. N/C	2. ANODE	2. CATHODE	2. SOURCE
3. COLLECTOR	3. CATHODE	3. CATHODE	3. ANODE	3. DRAIN

DOCUMENT NUMBER:	98AON23134D	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED	
DESCRIPTION:	SOT-1123, 3-LEAD, 1.0X0	.6X0.37, 0.35P	PAGE 1 OF 1
ON Semiconductor and (III) are trac	lemarks of Semiconductor Components Indu	stries IIC dba ON Semiconductor or its subsidiaries in the United States	and/or other countries

on Semiconductor are verse the right to make changes without further notice to any products herein. ON Semiconductor in makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

DATE 29 NOV 2011

- NOTES:
- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE
- MINIMUM THICKNESS OF BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. 4.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.34	0.40	
b	0.15	0.28	
b1	0.10	0.20	
С	0.07	0.17	
D	0.75	0.85	
Е	0.55	0.65	
е	0.35	0.40	
HE	0.95	1.05	
L	0.185 REF		
L2	0.05	0.15	

GENERIC **MARKING DIAGRAM\*** 

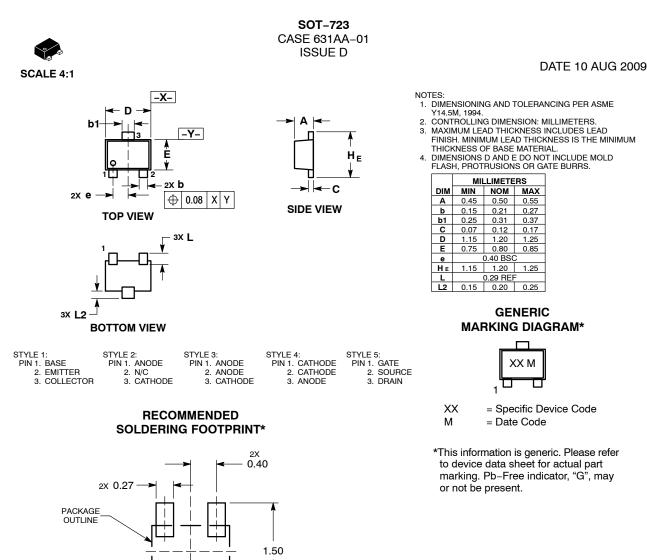
= Specific Device Code Х Μ = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " .", may or may not be present.

© Semiconductor Components Industries, LLC, 2019





3X 0.52 - - 0.36 DIMENSIONS: MILLIMETERS

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

 
 DOCUMENT NUMBER:
 98AON12989D
 Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

 DESCRIPTION:
 SOT-723
 PAGE 1 OF 1

 ON Semiconductor and ON semiconductor components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent\_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>